

TOSHIBA HIGH EFFICIENCY DIODE STACK (HED) SILICON EPITAXIAL TYPE

16DL2CZ47A, 16FL2CZ47A

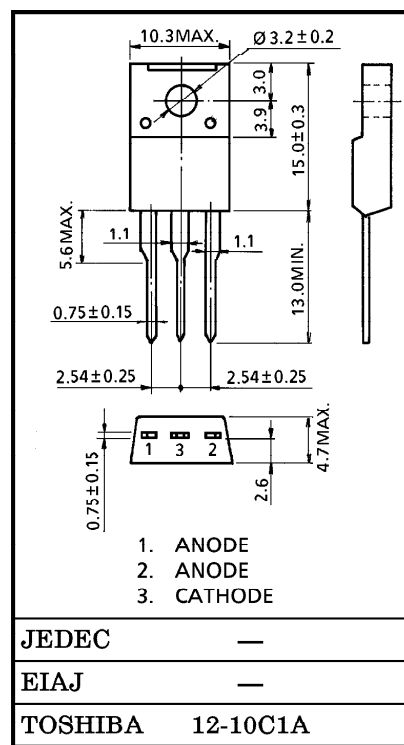
SWITCHING TYPE POWER SUPPLY APPLICATION
CONVERTER & CHOPPER APPLICATION

Unit in mm

- Repetitive Peak Reverse Voltage : $V_{RRM}=200, 300V$
- Average Output Rectified Current : $I_O=16A$
- Ultra Fast Reverse-Recovery Time : $t_{rr}=35ns$ (Max.)
- Low Switching Losses and Output Noise.

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	200	V
16DL2CZ47A		100	
16FL2CZ47A			
Average Output Rectified Current (Full Sine Waveform)	I_O	16	A
Peak One Cycle Surge Forward Current (Non-Repetitive)	I_{FSM}	80 (50Hz)	A
		88 (60Hz)	
Junction Temperature	T_j	-40~150	°C
Storage Temperature Range	T_{stg}	-40~150	°C
Screw Torque	—	0.6	N·m



JEDEC	—
EIAJ	—
TOSHIBA	12-10C1A

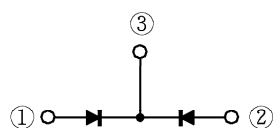
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Weight : 2.0g

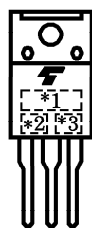
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage (Note 1)	V_{FM}	$I_{FM}=8A$	—	—	0.98	V
16DL2CZ47A			—	—	1.3	
16FL2CZ47A						
Repetitive Peak Reverse Current (Note 1)	I_{RRM}	$V_{RRM}=\text{Rated}$	—	—	50	μA
Reverse Recovery Time (Note 1)	t_{rr}	$I_F=2.0A, di/dt=-50A/\mu s$	—	—	35	ns
Forward Recovery Time (Note 1)	t_{fr}	$I_F=1.0A$	—	—	100	ns
Thermal Resistance	$R_{th(j-c)}$	DC Total, Junction to Case	—	—	3.3	°C/W

(Note 1) A value of one cell.

POLARITY



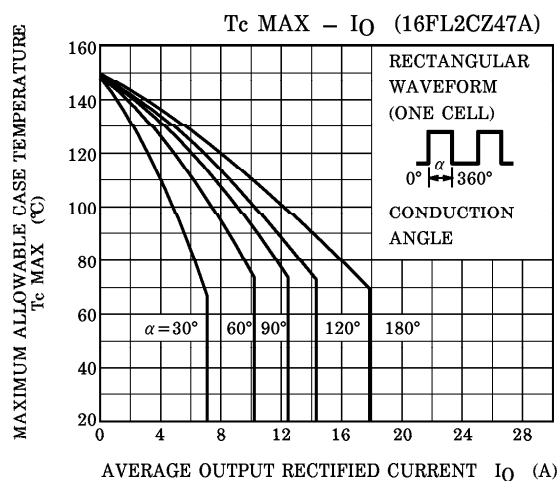
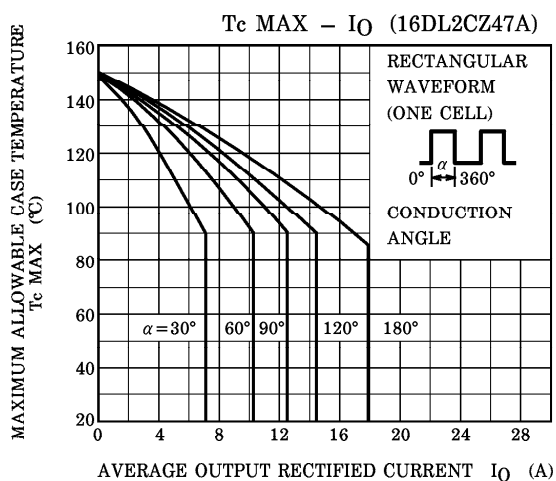
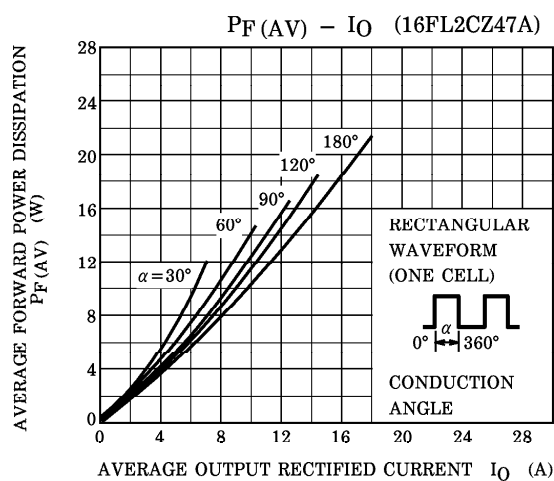
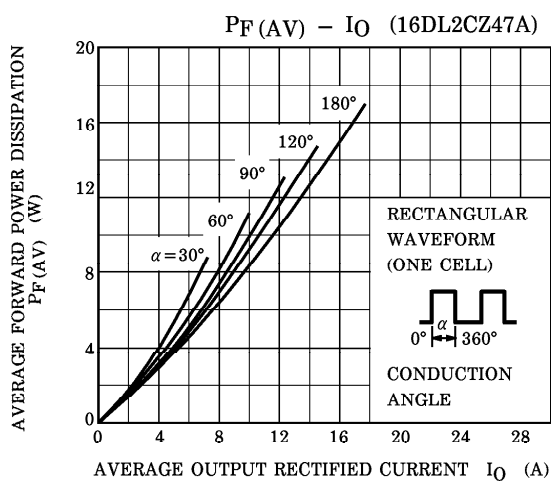
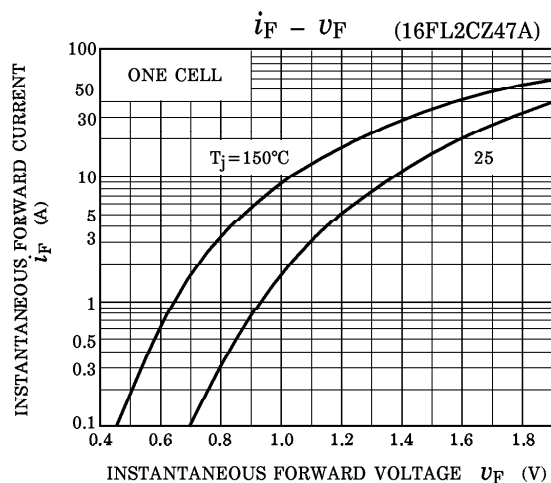
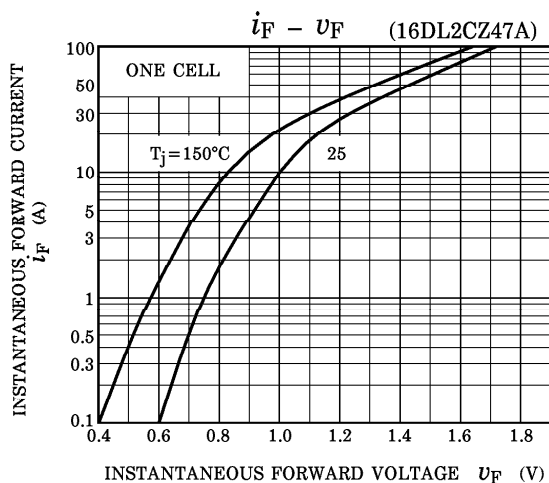
MARKING



*1	MARK	16DL2CZ	TYPE	16DL2CZ47A
		16FL2CZ		16FL2CZ47A
*2	A			
*3	Lot Number			
	□□—Month (Starting from Alphabet A)			
	—Year (Last Number of the Christian Era)			

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